

TAN250A

250 Watts, 50 Volts, Pulsed Avionics 960 - 1215 MHz

GENERAL DESCRIPTION

The TAN250A is a high powered COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 960-1215 MHz. The device has gold thin-film metallization and diffused ballasting for proven highest MTTF. The transistor includes input and output prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.

CASE OUTLINE 55AW, Style 1

ABSOLUTE MAXIMUM RATINGS

Maximum Power Dissipation

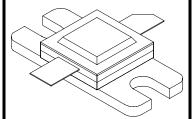
Device Dissipation @25°C 575 W

Maximum Voltage and Current

Collector to Base Voltage (BV_{ces}) 60 V Emitter to Base Voltage (BV_{ebo}) 4.0 V Collector Current (I_c) 30 A

Maximum Temperatures

Storage Temperature -65 to +200 °C Operating Junction Temperature +200 °C



ELECTRICAL CHARACTERISTICS @ 25°C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
P _{out}	Power Out	F = 960-1215 MHz	250			W
P _{in}	Power Input	Vcc = 50 Volts			60	W
P_{g}	Power Gain	$PW = 20 \mu sec$	6.2	7.0		dB
η_c	Collector Efficiency	DF = 5%		40		%
VSWR	Load Mismatch Tolerance	F = 1090 MHz			5:1	

FUNCTIONAL CHARACTERISTICS @ 25°C

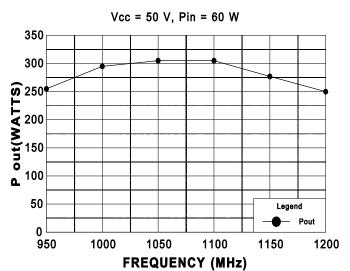
BV_{ebo}	Emitter to Base Breakdown	Ie = 20 mA	4.0		V
$\mathrm{BV}_{\mathrm{ces}}$	Collector to Emitter Breakdown	Ic = 25 mA	60		V
h_{FE}	DC – Current Gain	Vce = 5V, $Ic = 1 A$	10		
θjc^2	Thermal Resistance			.3	°C/W

NOTE 1: At rated output power and pulse conditions

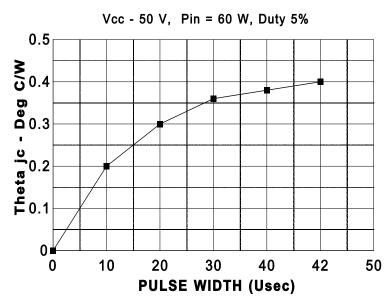
Revision A, August 2010

^{2.} At rated pulse conditions

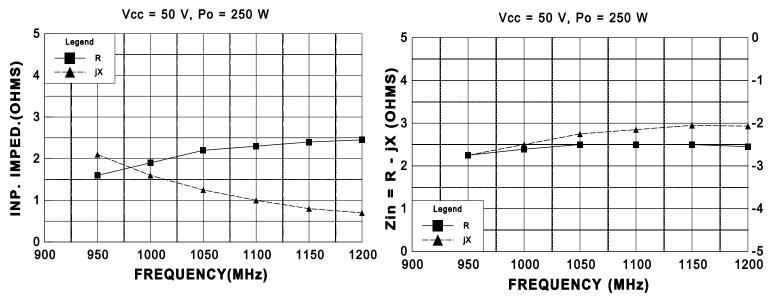
BROADBAND POWER OUTPUT vs FREQUENCY



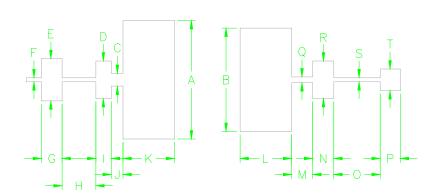
THERMAL RESISTANCE vs PULSE WIDTH



SERIES INPUT IMPEDANCE vs FREQUENCY SERIES LOAD IMPEDANCE vs FREQUENCY

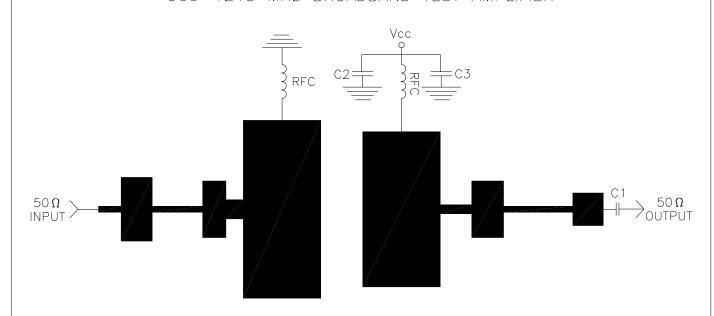


June 1996



DIM	INCHES		
Α	1.260		
B C	1.100		
С	.135		
D	.400		
Е	.450		
F	.042		
G	.220		
Н	.360		
I	.160		
J	.125		
K	.550		
L	.550		
М	.225		
N	.250		
0	.495		
Р	.215		
Q	.062		
R	.400		
S	.042		
Т	.230		

960-1215 MHz BROADBAND TEST AMPLIFIER



PCB-.015" TFE, 2 oz, CU. type "GT", $\varepsilon_{\rm r}$ = 2.55 C1, C2 - 82pf Chip C3-250 MFD

DWG NO.

TAN 250A

